

**APPLICATION**

- I/O ESD protection for mobile handsets, notebook, PDAs, etc.
- EMI filtering for data ports in cell phones, PDAs, notebook computers
- EMI filtering for LCD, camera and chip-to-chip data lines

**FEATURES**

- EMI/RFI filtering
- ESD Protection to IEC 61000-4-2 Level 4
- Low insertion loss
- Good attenuation of high frequency signals
- Low clamping voltage
- Low operating and leakage current
- Six elements in one package

**DESCRIPTION**

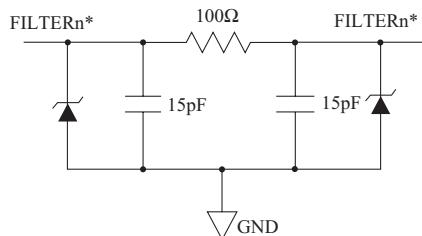
PV1015UDF12B is an EMI filter array with electrostatic discharge (ESD) protection, which integrates six pi filters (C-R-C). These parts include ESD protection diodes on every pin, providing a very high level of protection for sensitive electronic components that may be subjected to electrostatic discharge.

The PV1015UDF12B provides the recommended line termination while implementing a low pass filter to limit EMI levels and providing ESD protection which exceeds IEC 61000-4-2 level 4 standard. The UDFN package is a very effective PCB space occupation and a very thin package (0.4mm Pitch, 0.5mm height)

**MAXIMUM RATING (Ta=25 °C)**

CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Power Per Resistor	P <sub>R</sub>	100	mW
Power Dissipation	*P <sub>D</sub>	600	
Junction Temperature	T <sub>j</sub>	150	
Storage Temperature	T <sub>stg</sub>	-55 150	

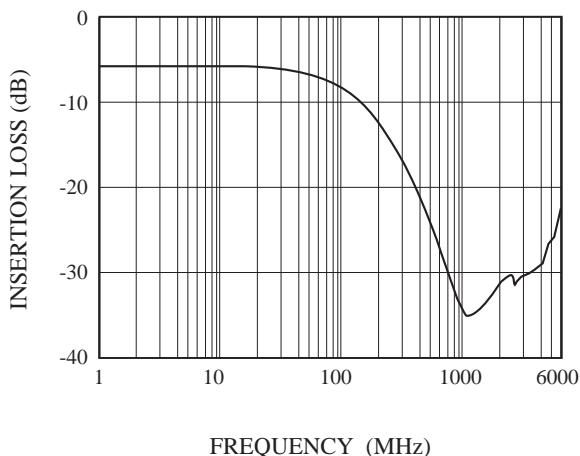
\* Total Package Power Dissipation

**EQUIVALENT CIRCUIT****ELECTRICAL CHARACTERISTICS (Ta=25 °C)**

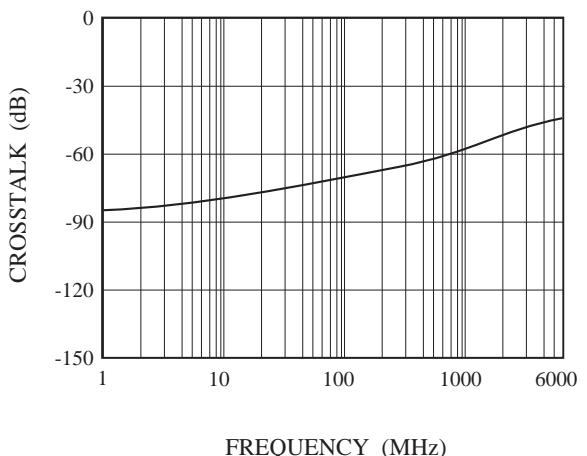
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Reverse Stand-Off Voltage	V <sub>RWM</sub>	-	-	-	5	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>f</sub> =1mA	6	-	-	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> =3.3V	-	-	1.0	µA
Cutoff Frequency	f <sub>c-3dB</sub>	V <sub>Line</sub> =0V, Z <sub>SOURCE</sub> =50Ω, Z <sub>LOAD</sub> =50Ω	-	110	-	MHz
Channel Resistance	R <sub>LINE</sub>	Between Input and Output	80	100	120	
Capacitance	C <sub>LINE</sub>	V <sub>Line</sub> =0V DC, 1MHz, Between I/O Pins and GND	36	45	54	pF
		V <sub>Line</sub> =2.5V, 1MHz, Between I/O Pins and GND	24	30	36	

# PV1015UDF12B

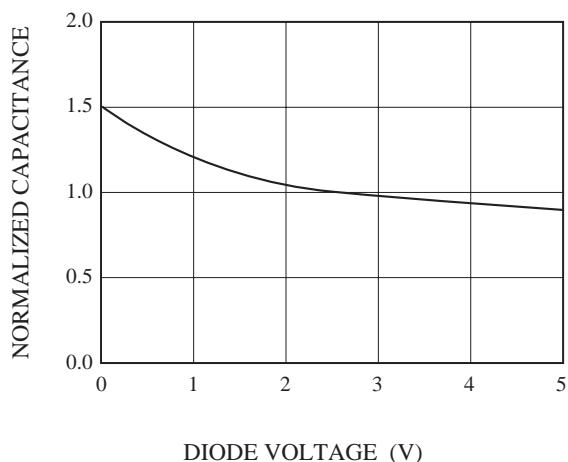
S<sub>21</sub> - FREQUENCY



ANALOG CROSSTALK



DIODE CAPACITANCE vs. INPUT VOLTAGE



R<sub>Line</sub> - TEMPERATURE

